P-Channel 20-V (D-S) MOSFET

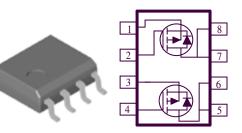
These miniature surface mount MOSFETs utilize a high cell density trench process to provide low $r_{DS(on)}$ and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

PRODUCT SUMMARY					
$V_{DS}(V)$	$r_{DS(on)} m(\Omega)$	$I_{D}(A)$			
	$52 @ V_{GS} = -4.5V$	-4.9			
-20	89 @ $V_{GS} = -2.5V$	-4.0			
	124 @ Vgs = -1.8V	-3.6			

- Low r_{DS(on)} provides higher efficiency and extends battery life
- Low thermal impedance copper leadframe SOIC-8 saves board space
- Fast switching speed
- High performance trench technology







ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C UNLESS OTHERWISE NOTED)							
Parameter			Maximum	Units			
Drain-Source Voltage			-20	V			
Gate-Source Voltage			±12	V			
	T _A =25°C	Τ_	-5.2				
Continuous Drain Current ^a	$T_A=25^{\circ}C$ $T_A=70^{\circ}C$	1D	-4.1	A			
Pulsed Drain Current ^b	I_{DM}	±50					
Continuous Source Current (Diode Conduction) ^a	I_S	-2.1	A				
Parama Discipation a	$T_A=25^{\circ}C$ $T_A=70^{\circ}C$	D-	2.1	w			
Power Dissipation ^a	$T_A=70^{\circ}C$	Гр	1.3	**			
Operating Junction and Storage Temperature Range			-55 to 150	°C			

THERMAL RESISTANCE RATINGS						
Parameter	Symbol	Maximum	Units			
Maximum Junction-to-Case ^a	t <= 5 sec	$R_{ heta JC}$	40	°C/W		
Maximum Junction-to-Ambient ^a	t <= 5 sec	$R_{ heta JA}$	60	°C/W		

Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

SPECIFICATIONS (T _A = 25°C UNLESS OTHERWISE NOTED)							
Donometer	Sample of Total Conditions		Limits			Unit	
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static							
Gate-Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_{D} = -250 \text{ uA}$	-0.7				
Gate-Body Leakage	I_{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 12 \text{ V}$			±100	nA	
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = -16 \text{ V}, V_{GS} = 0 \text{ V}$			-1	uA	
	D33	$V_{DS} = -16 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			-5		
On-State Drain Current ^A	$I_{D(on)}$	$V_{DS} = -4.5 \text{ V}, V_{GS} = -10 \text{ V}$	-20			A	
		$V_{GS} = -4.5 \text{ V}, I_D = -4.9 \text{ A}$			52		
Drain-Source On-Resistance ^A	$r_{DS(on)}$	$V_{GS} = -2.5 \text{ V}, I_D = -4.0 \text{ A}$			89	mΩ	
		$V_{GS} = -1.8 \text{ V}, I_D = -3.6 \text{ A}$			124		
Forward Tranconductance ^A	g_{fs}	$V_{DS} = -15 \text{ V}, I_{D} = -4.9 \text{ A}$		20		S	
Diode Forward Voltage	V_{SD}	$I_S = 2.5 \text{ A}, V_{GS} = 0 \text{ V}$		-0.6		V	
Dynamic ^b							
Total Gate Charge	Q_{g}	$V_{DS} = -10 \text{ V}, V_{GS} = -4.5 \text{ V},$		16.7			
Gate-Source Charge	Q_{gs}	$V_{DS} = -10 \text{ V}, V_{GS} = -4.5 \text{ V},$ $I_{D} = -4.9 \text{ A}$		1.8		nC	
Gate-Drain Charge	Q_{gd}	тр – -4.9 А		1.9			
Turn-On Delay Time	$t_{d(on)}$			7			
Rise Time	t _r	V_{DD} = -10 V, R_{L} = 6 Ω , ID = -1 A,		13		nS	
Turn-Off Delay Time	$t_{d(off)}$	VGEN = -4.5 V		14		113	
Fall-Time	t_{f}			9			

Notes

- a. Pulse test: $PW \le 300$ us duty cycle $\le 2\%$.
- b. Guaranteed by design, not subject to production testing.

FREESCAE reserves the right to make changes without further notic e to any products herein. freescalemakes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does freescale assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in freescale data sheet s and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. freescaledoes not convey any license under its patent rights nor the rights of others. freescale products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications int sustain life, or for any other application in which the failure of the freescale product could create a situation where personal inju
Should Buyer purchase or use freescale products for any such uninte nded or unauthorized application, Buyer shall indemnify and hold freescale and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that freescale was negligent regarding the design or manufacture of the part. freescale is an Equal Opportunity/Affirmative Action Employer.

Freescale *AO4801/MC4801*

Typical Electrical Characteristics (P-Channel)

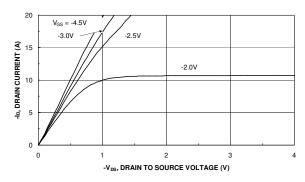


Figure 1. Output Characteristics

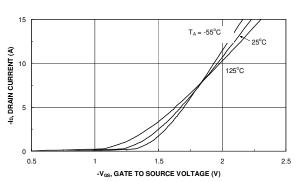


Figure 2. Transfer Characteristics

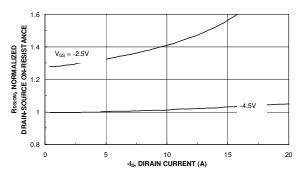


Figure 3. On-Resistance vs. Drain Current

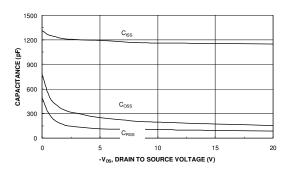


Figure 4. Capacitance

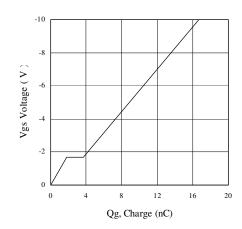


Figure 5. Gate Charge

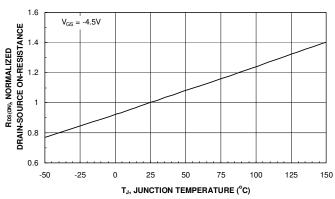
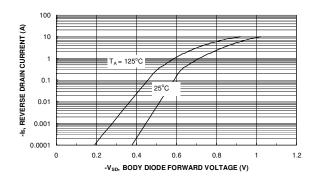


Figure 6. On-Resistance vs. Junction Temperature

Freescale AO4801/MC4801

Typical Electrical Characteristics (P-Channel)



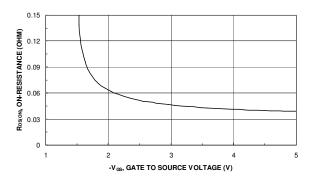


Figure 7. Source-Drain Diode Forward Voltage

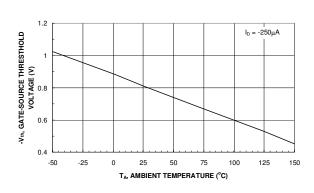


Figure 8. On-Resistance with Gate to Source Voltage

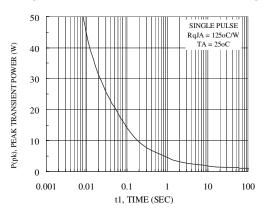


Figure 9. Vth Gate to Source Voltage Vs Temperature

Figure 10. Single Pulse Maximum Power Dissipation

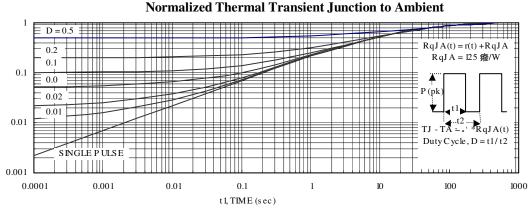
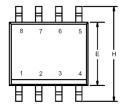


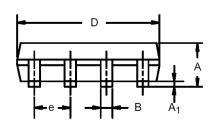
Figure 11. Transient Thermal Response Curve

Freescale AO4801/MC4801

Package Information

SO-8: 8LEAD





	MILLIN	IETERS	INCHES		
Dim	Min	Max	Min	Max	
Α	1.35	1.75	0.053	0.069	
A ₁	0.10	0.20	0.004	0.008	
В	0.35	0.51	0.014	0.020	
С	0.19	0.25	0.0075	0.010	
D	4.80	5.00	0.189	0.196	
E	3.80	4.00	0.150	0.157	
е	1.27 BSC		0.050 BSC		
Н	5.80	6.20	0.228	0.244	
h	0.25	0.50	0.010	0.020	
L	0.50	0.93	0.020	0.037	
q	0°	8°	0°	8°	

